

HJR High Energy Resistor

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Huizhou KKT electronics Co.,Ltd

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KKT HJR High Energy Resistor



Custom HJR High Energy resistor stacks employ heavy-duty components for mechanical mounting, electrical isolation and termination. yielding ratings to thousands of kilojoules of single-surge energy.

High Energy resistors offer unsurpassed performance in high energy and high voltage applications. These non-inductive, ceramic composite resistors are designed for pulse shaping, crowbar, capacitor charg /discharge… any application requiring low inductance along with extremes of voltage and energy. They are ideally suited for use in pulsed power systems, where these resistors distribute energy uniformly throughout their structure for low thermal stress. The standard, high-temperature silicone coating enhances high voltage performance in air. Optional configurations optimize performance in other gaseous or fluid dielectrics. These resistors are also available as a solid disk without center bore.

Features

I .100% Active Material II .High Surge Energy Rating III .High Voltage Withstand IV .Essentially Non-Inductive V .Wide Resistivity Range VI .Wide Range of Geometries VI .Air / Oil / SF6 Environments VII Single Disc or Modular Assemblies IX .Custom Solutions Readily Available X .Free Design Service

Applications

HJR High Energy resistors are most often usedfor low repetition rate discharge, crowbar, pulse shaping or other impulse duty. In practice, a resistor or combination is selected to yield no more than 100oC rise for the expected applied energy. Because of the large mass, a relatively long cooling time is required between pulses, or additional heat capacity must be allowed for.Our applications spreadsheet (MS Excel,available on diskette) can beused to easily model heat-up and cool-down profiles for your specific application.

Ordering Information

Example:

HJR	30	Κ	80R00	5P
(1)	(2)	(3)	(4)	(5)
Series Name	Power Rating	Resistance Tolerance	Resistance Value	Series

(1)Style:HJR SERIES

(2)Power Rating: 30=30W、50=50W、75=75W、95=95W......

(3)Tolerance: $K = \pm 10\%$, $M = \pm 20\%$

(4)Resistance Value:0R5=0.5Ω、 80R00=80R、 100R00=100R、

(5)Series:5P=5PCS、8P=8PCS、10P=10PCS

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Reference Standards

JIS C 5201-1

Dimensions



Part]	Dimension	s(Individ	lual un	it)	
Part No.	Do	Di	Thickness	volume	Energy	weight
	mm	mm	mm	cm ³	KJ	g
HJR30	32 ± 1	11 ± 1		27	5	90
HJR50	50 ± 1	20 ± 1		42	12	90
HJR75	75 ± 1	34 ± 2		93	28	190
HJR95	95 ± 1	34 ± 2	25 ± 1	160	56	190
HJR112	112 ± 1	34 ± 2		220	75	190
HJR125	125 ± 1	34 ± 2		295	85	650
HJR150	150 ± 1	34 ± 2		420	110	950

Power And Resistance etc

Part Part No.	Resistance Range (Ω)	Max. Energy 2 (KJ)	Max. Impulse Volts 3 (kV)
HJR30	0.5-100R	5	18KV
HJR50	0.5-100R	12	20KV
HJR75	0.5-100R	28	24KV
HJR95	0.5~90R	56	26KV
HJR112	0.5~80R	75	27KV
HJR125	0.5~60R	75	28KV
HIR150	0.5~50R	110	30KV

Notes:

1 Custom thickness available, affects ratings

2 Single impulse to cause 125°C temperature rise

3 Standardized for 50Ω resistor in air, $1.2/50\mu$ sec pulse width

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Power Dissipation

Heat generated by the High Energy Disk Resistors is dissipated mainly by radiation and convection from the exposed surface areas. Within restricted domains, mathematical models may be employed to permit heat transfer estimations.

Higher power dissipation is achieved using conduction cooling through either one or both mounting surfaces using] Air heat sink] Water cooled heat sink
Radiation and Convection	W a = $0.00026(\Delta T)$ 1.4 W a = Watts/Units Exposed Surface Area (W.cm -2) $\Delta T = 50^{\circ}$ C to 175°C, D o =1.9 to 15.1 cm, Ambient 25°C
Recommended Operation Temperatures	Disc diameters $\leq 11.2 \text{ cm} \leq 300 \text{ °C}$ (Infrequent Operation) Disc diameters $> 11.2 \text{ cm} \leq 250 \text{ °C}$ (Infrequent Operation) All Disc diameters $\leq 150 \text{ °C}$ (Continuous Operation)

Impulse Voltage

Maximum impulse voltage	☐ Mainly—Resistance value and pulse width		
is a function of:	Lesser Extent—Surface temperature and dielectric medium		
Rocietivity Rango-o	3Ω cm to 30000Ω cm		
Resistivity Range Q	$\varrho = R \ge A/L$		
	R = Resistance value, A = Surface area, L = Length		
Temperature Coefficient	-0.05% to $-0.15%$ per °C rise(depending on Resistivity value)		
Voltage Coefficient	\Box -0.5% to -7.5% per kV/cm(for ϱ domain 10 Ω cm to 7500 Ω cm)		
	SF6 V wk = 8.0 x $1.2\sqrt{Log(R/2.54 \text{ x A/L})}$ kV/cm $1.2/50\mu$ s Waveform		
Maximum Working Voltage Withstar	AIR V wk = 4.3 x $1.2 \sqrt{\text{Log}(\text{R}/2.54 \text{ x A/L})}$ kV/cm $1.2/50 \mu$ s Waveform		
per cm of Disk Length (V wk)	AIR V wk = $3.0 \times \text{Log}(\text{R}/2.54 \times \text{A/L})$ 1.25 kV/cm $50/1000 \mu \text{s}$ Waveform		
	AIR V wk = $1.5 \times (Log(R/2.54 \times A/L)^{1.20} \text{ kV/cm} 100/10000 \mu s Waveform}$		

Derating Curve

Maximum impulse voltage is mainly a function of resistance value and pulse width, and to a lesser extent, surface temperature and dielectric medium. The chart below shows the range of maximum impulse voltage for the standardized 1.2/ 50 μ sec. pulse width in air.,which indicates the range and relative impulse ratings for thevarious standard sizes.Our applications group can assist you in assessing the correct parameters for your application.



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